



Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
00)/	29mΩ @ V _{GS} = 10V	6.5A
20V	$35m\Omega @ V_{GS} = 4.5V$	5.2A

Description

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- General Purpose Interfacing Switch
- Power Management Functions

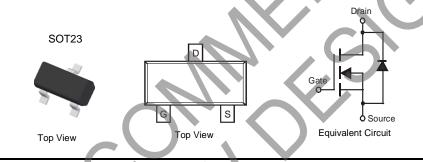
N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (Approximate)



Ordering Information (Note 4)

Part Number	Qualification	Case	Packaging
DMG3420U-7	Standard	SOT23	3000/Tape & Reel

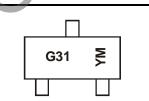
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 - 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4.. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:



 $\begin{array}{l} G31 = \mbox{Product Type Marking Code} \\ \mbox{YM or } \overline{Y}M = \mbox{Date Code Marking} \\ \mbox{Y or } \overline{Y} = \mbox{Year (ex: G = 2019)} \\ \mbox{M = Month (ex: 9 = September)} \end{array}$

Date Code Key												
Year	2009	~	2019	2020	202	21 20)22	2023	2024	2025	2026	2027
Code	W	~	G	Н			J	K	L	М	Ν	0
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



DMG3420U

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characte	eristic		Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	20	V
Gate-Source Voltage		V _{GSS}	±12	V	
Continuous Drain Current (Note 5)	Steady State	T _A = +25°C T _A = +85°C	۱ _D	5.47 3.43	A
Pulsed Drain Current (Note 6)			I _{DM}	20	А

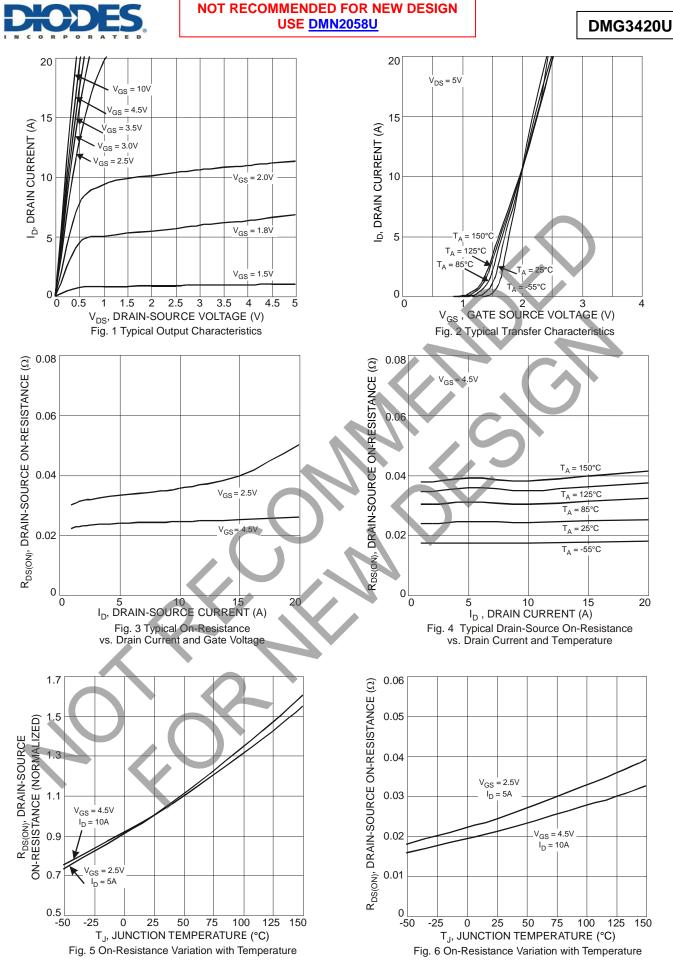
Thermal Characteristics			
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	0.74	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5)	R _{θJA}	167	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	℃

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	20	-	-	V	V _{GS} = 0V, I _D = 250µA	
Zero Gate Voltage Drain Current T _J = +25°C	IDSS		—	1.0	μA	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	lgss		—	±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	0.5	0.95	1.2	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
			21	29		$V_{GS} = 10V, I_D = 6A$	
Static Drain-Source On-Resistance			25	35		$V_{GS} = 4.5V, I_D = 5A$	
Static Drain-Source On-Resistance	R _{DS(ON)}		34	48	mΩ	$V_{GS} = 2.5V, I_D = 4A$	
			65	91		V _{GS} = 1.8V, I _D = 2A	
Forward Transfer Admittance	Y _{fs}	—	9	_	S	$V_{DS} = 5V, I_D = 3.8A$	
Diode Forward Voltage	VsD		0.75	1.0	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 8)						·	
Input Capacitance	C _{iss}	_	434.7	-	pF		
Output Capacitance	Coss	—	69.1	_	pF	V _{DS} = 10V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	—	61.2	_	pF	1 - 1.00012	
Gate Resistance	Rg	_	1.53		Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Qg	—	5.4	_	nC		
Gate-Source Charge	Q _{gs}	_	0.9		nC	$V_{GS} = 4.5V, V_{DS} = 10V,$	
Gate-Drain Charge	Q _{gd}		1.5		nC	I _D = 6A	
Turn-On Delay Time	t _{D(ON)}	_	6.5		ns		
Turn-On Rise Time	t _R		8.3	_	ns	V _{DD} = 10V, V _{GS} = 5V,	
Turn-Off Delay Time	t _{D(OFF)}		21.6	_	ns	$R_L = 1.7\Omega, R_g = 6\Omega$	
Turn-Off Fall Time	t⊢		5.3	—	ns		

Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Repetitive rating, pulse width limited by junction temperature.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to production testing.

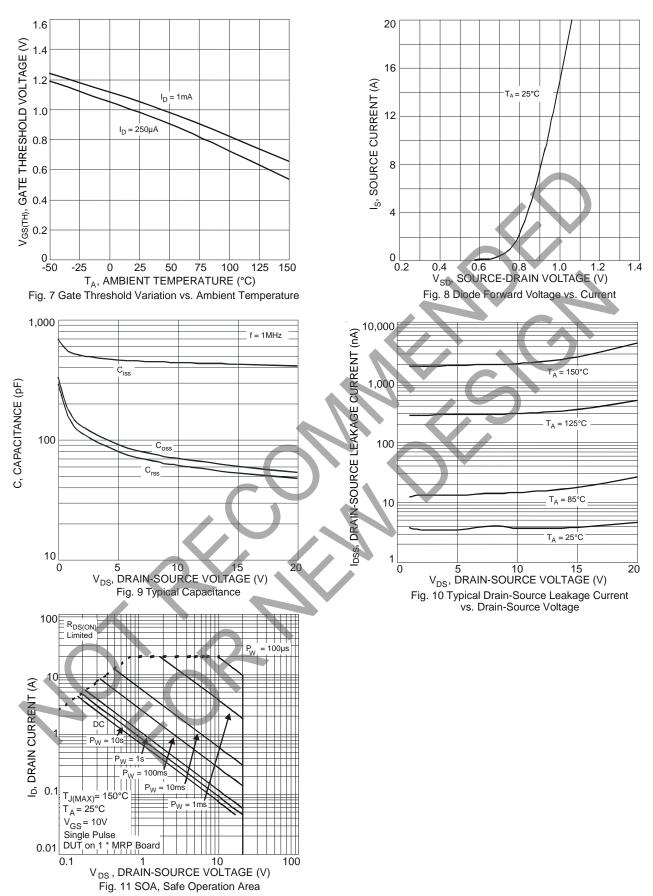
Notes:





NOT RECOMMENDED FOR NEW DESIGN USE <u>DMN2058U</u>

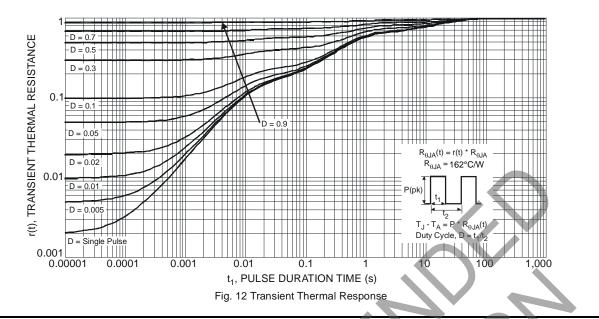
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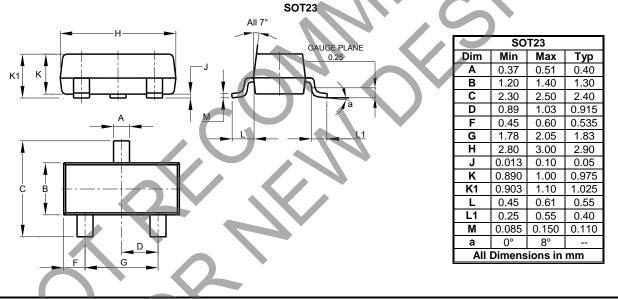
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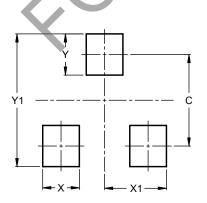
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SO123

Dimensions	Value (in mm)
C	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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